

DATA SHEET

BGY89 CATV amplifier module

Product specification
File under Discrete Semiconductors, SC16

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Philips Semiconductors



PHILIPS

CATV amplifier module

BGY89

FEATURES

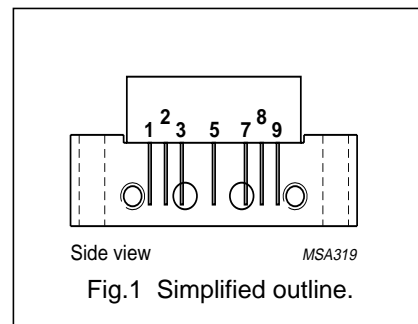
- Excellent linearity
- Extremely low noise
- Silicon nitride passivation
- Rugged construction
- TiPtAu metallized crystals ensure optimal reliability.

DESCRIPTION

Hybrid amplifier module for CATV systems operating over a frequency range of 40 to 450 MHz at a voltage supply of 24 V (DC). The module is intended for use as a line-extender.

PINNING - SOT115J

PIN	DESCRIPTION
1	input
2	common
3	common
5	+V _B
7	common
8	common
9	output



QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
G _p	power gain	f = 50 MHz	37	–	39	dB
I _{tot}	total current consumption (DC)	V _B = 24 V	–	320	340	mA

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
V _i	RF input voltage	–	55	dBmV
T _{stg}	storage temperature	–40	+100	°C
T _{mb}	operating mounting base temperature	–20	+100	°C

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CHARACTERISTICSBandwidth 40 to 450 MHz; $V_B = 24$ V; $T_{mb} = 35$ °C; $Z_S = Z_L = 75$ Ω .

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
G _p	power gain	f = 50 MHz	37	–	39	dB
		f = 450 MHz	37	–	–	dB
SL	slope cable equivalent	f = 40 to 450 MHz	0	–	2.5	dB
FL	flatness of frequency response	f = 40 to 450 MHz	–	–	±0.4	dB
S ₁₁	input return losses	f = 40 to 80 MHz	20	–	–	dB
		f = 80 to 160 MHz	19	–	–	dB
		f = 160 to 450 MHz	18	–	–	dB
S ₂₂	output return losses	f = 40 to 80 MHz	20	–	–	dB
		f = 80 to 160 MHz	19	–	–	dB
		f = 160 to 450 MHz	18	–	–	dB
S ₂₁	phase response	f = 50 MHz	–45	–	+45	deg
CTB	composite triple beat	60 channels flat; V _o = 46 dBmV; measured at 445.25 MHz	–	–	–58	dB
X _{mod}	cross modulation	60 channels flat; V _o = 46 dBmV; measured at 55.25 MHz	–	–	–58	dB
CSO	composite second order distortion	60 channels flat; V _o = 46 dBmV; measured at 446.5 MHz	–	–	–58	dB
d ₂	second order distortion	note 1	–	–	–70	dB
V _o	output voltage	d _{im} = –60 dB; note 2	63	–	–	dBmV
F	noise figure	f = 450 MHz	–	–	5.5	dB
I _{tot}	total current consumption (DC)	note 3	–	320	340	mA

Notes

1. $f_p = 55.25$ MHz; $V_p = 46$ dBmV;
 $f_q = 343.25$ MHz; $V_q = 46$ dBmV;
measured at $f_p + f_q = 398.5$ MHz.
2. Measured according to DIN45004B:
 $f_p = 440.25$ MHz; $V_p = V_o = 63$ dBmV;
 $f_q = 447.25$ MHz; $V_q = V_o - 6$ dB;
 $f_r = 449.25$ MHz; $V_r = V_o - 6$ dB;
measured at $f_p + f_q - f_r = 438.25$ MHz.
3. The module normally operates at $V_B = 24$ V, but is able to withstand supply transients up to 30 V.



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